



20V PNP POWER SWITCHING TRANSISTOR IN SOT323

Features

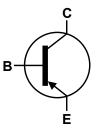
- BV_{CEO} > -20V
- I_C = -1A Continuous Collector Current
- I_{CM} = -3A Peak Pulse Current
- Low Saturation Voltage -250mV Max @ I_C = -1A.
- R_{CE(SAT)} = 200mΩ @ 1A for a Low Equivalent On-Resistance
- 500mW Power Dissipation
- Excellent h_{FE} Characteristics up to 3A
- Complementary NPN Type: ZUMT618
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

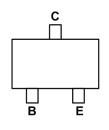
- Case: SOT323
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight: 0.006 grams (approximate)







Device Symbol



Top View Pin-Out

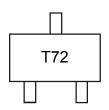
Ordering Information (Notes 4)

Device	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per reel
ZUMT718TA	AEC-Q101	T72	7	8	3,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



T72 = Product Type Marking Code



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-20	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-7	V
Peak Pulse Current	I _{CM}	-3	Α
Continuous Collector Current	Ic	-1	Α
Base Current	I _B	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D	385	mW	
Power Dissipation	(Note 6)	P_{D}	500	11100	
Thermal Decistores Lunction to Ambient	(Note 5)	D	325	0000	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ hetaJA}$	250	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	350	°C/W	
Operating and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C		

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with collector lead on 10mm x 8mm 1oz copper that is on a single-sided 0.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the collector lead is on a 25mm x 25mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



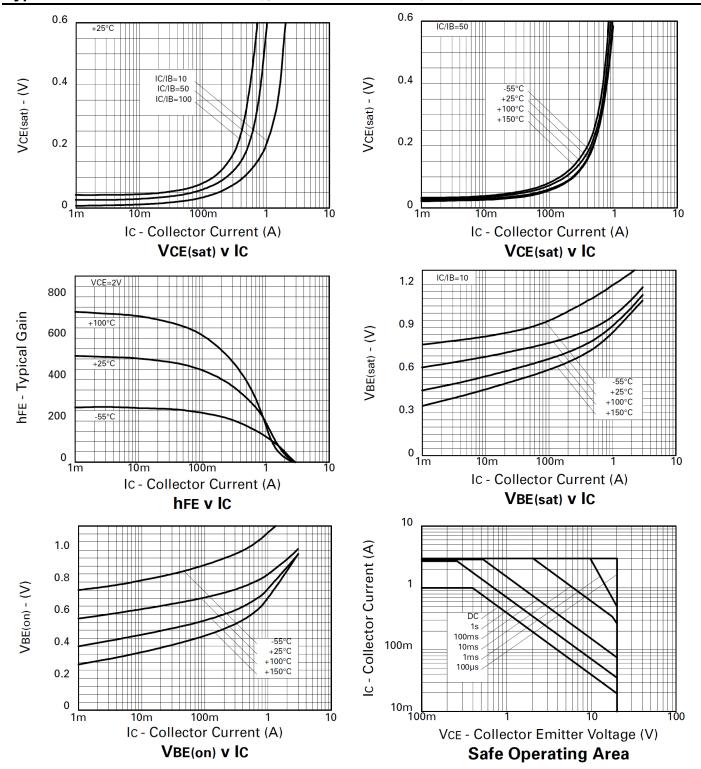
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Collector-Base Breakdown Voltage	V _{CBO}	-20	_	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage	V _{CEO}	-20	_	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	V _{EBO}	-7	_	_	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CBO}	_	_	-10	nA	V _{CB} = -15V
Emitter-Base Cutoff Current	I _{EBO}	_	_	-10	nA	V _{EB} = -4.0V
Collector-Emitter Cutoff Current	I _{CES}	_	_	-10	nA	V _{CES} = -15V
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h _{FE}	300 300 200 100 20	490 450 315 160 75	_	_	$\begin{split} I_C &= -10\text{mA}, \ V_{CE} = -2.0\text{V} \\ I_C &= -0.1\text{A} \ , \ V_{CE} = -2.0\text{V} \\ I_C &= -0.5\text{A}, \ V_{CE} = -2.0\text{V} \\ I_C &= -14, \ V_{CE} = -2.0\text{V} \\ I_C &= -1.5\text{A}, \ V_{CE} = -2.0\text{V} \\ I_C &= -1.5\text{A}, \ V_{CE} = -2.0\text{V} \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	-33.5 -80 -130 -180	-45 -110 -175 -250	mV mV mV	$\begin{split} I_C &= -0.1A,\ I_B = -10mA \\ I_C &= -0.25A,\ I_B = -10mA \\ I_C &= -0.5A,\ I_B = -20mA \\ I_C &= -1A,\ I_B = -100mA \end{split}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	-970	-1100	mV	I _C = -1A, I _B = 100mA
Base-Emitter Turn-On Voltage	V _{BE(ON)}	_	-850	-1100	mV	I _C = -1A, V _{CE} = -2.0V
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	_	11	_	pF	V _{CB} = -10V, f = 1MHz
Turn-On Time	t _(on)	_	60	_	ns	V _{CC} = -10V, I _C = -1A,
Turn-Off Time	t _(off)	_	135	_	ns	$I_{B1} = -I_{B2} = -100 \text{mA}$
Current Gain-Bandwidth Product	f _T	_	210	_	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



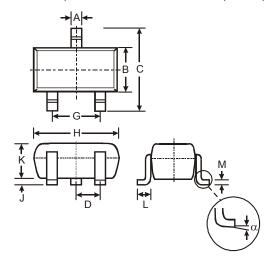
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

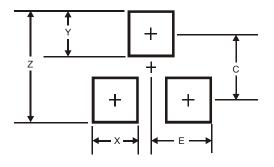
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT323					
Dim	Min	Max	Тур		
Α	0.25	0.40	0.30		
В	1.15	1.35	1.30		
С	2.00	2.20	2.10		
D	-	-	0.65		
G	1.20	1.40	1.30		
Н	1.80	2.20	2.15		
J	0.0	0.10	0.05		
K	0.90	1.00	1.00		
L	0.25	0.40	0.30		
М	0.10	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.8
X	0.7
Y	0.9
С	1.9
F	1.0



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